

DH_PBSE_TE Cooled Photodiode (1-5µm) Brochure



Overview

The DH_PBSE_TE cooled lead selenide photodiode offers wide spectral responsivity to 5µm and the convenience of thermo-electric cooling. Housing a 3x3mm active area lead selenide photodiode, the DH_PBSE_TE is operated in the photoconductive mode with the 215 high voltage supply whilst temperature control is ensured by the CPS1M.

Using an optically chopped input, the signal generated by this detector is best measured in using the 477 trans-impedance pre-amplifiers followed by the 496 DSP lock-in amplifier.

| <u>Core benefits</u> | <u>Features</u> |
|---|---|
| <ul style="list-style-type: none"> ✓ Covers the range of InSb with convenience of thermo-electric cooling ✓ Spectral coverage 1-5µm | <ul style="list-style-type: none"> ◆ Houses lead sulphide photodiode ◆ 3x3mm active area ◆ Operated in AC mode ◆ Compatible with Bentham's entire range of monochromators and accessories ◆ Suitable for free standing applications ◆ Recommended for use with 400 series detection electronics |

DH PBSE TE Cooled Photodiode (1-5 μ m) Specifications

Electro-optical

| | |
|--------------------------------|--|
| Material | Lead Selenide |
| Active area | 3x3 mm |
| Spectral response range | 1-5 μ m |
| Operating mode | Photoconductive |
| Shunt resistance (typ.) | 0.5-3M Ω |
| Peak wavelength (typ.) | 2600nm |
| Peak responsivity (typ.) | 2 x 10 ⁴ V.W ⁻¹ |
| NEP | <1.3 x 10 ⁻¹³ W.H ^{-1/2} |
| Maximum cooler current | 1.25A |
| Recommended chopping frequency | 175/ 225 Hz |
| Operating temperature | -10°C |
| Max. operating temperature | -20 to +60°C |

Mechanical

| | |
|---------------|--|
| Connector | BNC |
| Compatibility | Four M3 clearance holes (Bentham slit pattern) |
| Dimensions | |

Configuration Options

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|---------------|---|
| DH_PBSE_TE | Thermo-electrically cooled lead selenide photodiode |
| DH_PBSE_TE_QC | Thermo-electrically cooled lead selenide photodiode, quick change interface |

Wavelength vs Relative Spectral Responsivity

